# TOSHIBA

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VHC02F,TC74VHC02FN,TC74VHC02FT,TC74VHC02FK

#### Quad 2-Input NOR Gate

The TC74VHC02 is an advanced high speed CMOS 2-INPUT NOR GATE fabricated with silicon gate C<sup>2</sup>MOS technology.

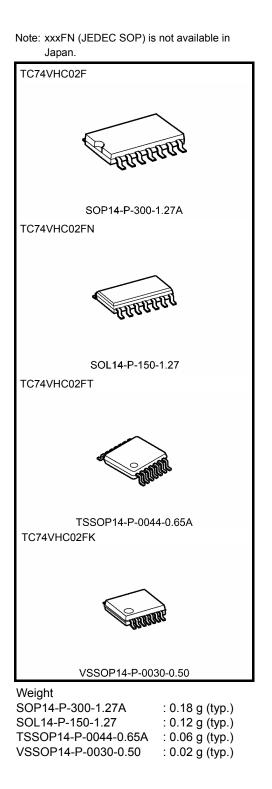
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

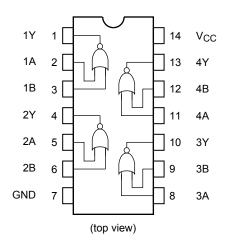
#### Features

- High speed:  $t_{pd}$  = 3.6 ns (typ.) at V<sub>CC</sub> = 5 V
- Low power dissipation:  $I_{CC} = 2 \ \mu A \ (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2 V to 5.5 V
- Low noise:  $V_{OLP} = 0.8 V (max)$
- Pin and function compatible with 74ALS02

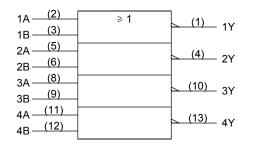


# <u>TOSHIBA</u>

#### **Pin Assignment**



#### **IEC Logic Symbol**



#### Truth Table

А	В	Y
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

# Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	IIК	-20	mA
Output diode current	I <sub>OK</sub>	±20	mA
DC output current	IOUT	±25	mA
DC V <sub>CC</sub> /ground current	ICC	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

# **Operating Ranges (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V <sub>CC</sub> = $3.3 \pm 0.3$ V)	ns/V
	uvuv	0 to 20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V)	115/ V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

# **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = −40 to 85°C		Unit			
				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	onit	
High-level input voltage	VIH	_		2.0 3.0 to 5.5	1.50 V <sub>CC</sub> × 0.7			1.50 V <sub>CC</sub> × 0.7	_	V	
Low-level input voltage	VIL	_		2.0 3.0 to 5.5			0.50 V <sub>CC</sub> × 0.3		0.50 V <sub>CC</sub> × 0.3	V	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -50 μA I <sub>OH</sub> = -4 mA	2.0 3.0 4.5 3.0	1.9 2.9 4.4 2.58	2.0 3.0 4.5		1.9 2.9 4.4 2.48		v
			I <sub>OH</sub> = −8 mA	4.5	3.94		-	3.80			
Low-level output V <sub>OL</sub> voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or	I <sub>OL</sub> = 50 μΑ	2.0 3.0 4.5		0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V	
		VIL	I <sub>OL</sub> = 4 mA I <sub>OL</sub> = 8 mA	3.0 4.5	_ _	_ _	0.36 0.36	_	0.44 0.44		
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	_	±1.0	μA	
Quiescent supply current	ICC	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_		2.0		20.0	μA	

#### AC Characteristics (input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics Sy	Symbol			st Condition		Ta = 25°C			Ta = −40 to 85°C						
			V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Min	Max						
timo		_	3.3 ± 0.3	15	_	5.6	7.9	1.0	9.5	ns					
	t <sub>pLH</sub> t <sub>pHL</sub>			50	_	8.1	11.4	1.0	13.0						
			5.0 ± 0.5	15	_	3.6	5.5	1.0	6.5						
				5.0 ± 0.5	5.0 ± 0.5	$5.0 \pm 0.5$	$5.0 \pm 0.5$	$5.0 \pm 0.5$	$5.0 \pm 0.5$	$5.0 \pm 0.5$	5.0 ± 0.5	$5.0 \pm 0.5$	50	_	5.1
Input capacitance	C <sub>IN</sub>	_			_	4	10	_	10	pF					
Power dissipation capacitance	C <sub>PD</sub>			(Note)	_	15				pF					

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

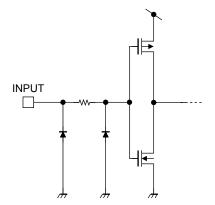
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$  (per gate)

#### Noise Characteristics (input: tr = tf = 3 ns)

Characteristics	Symbol	Test Condition	Ta =	Unit		
Characteristics	Symbol		V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic VOL	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.3	-0.8	V
Minimum high level dynamic input voltage	VIHD	C <sub>L</sub> = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0		1.5	V

# Input Equivalent Circuit

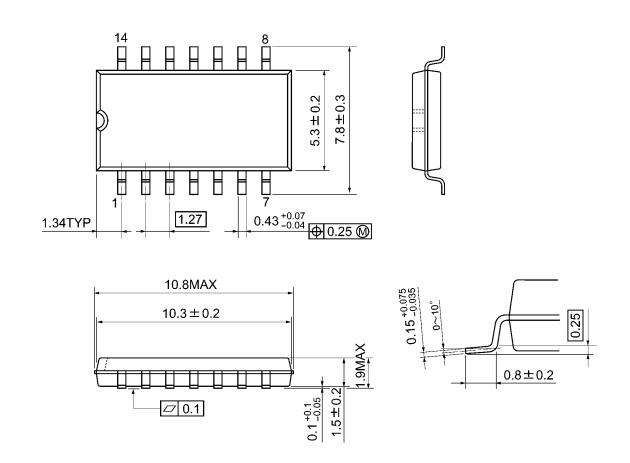




#### **Package Dimensions**

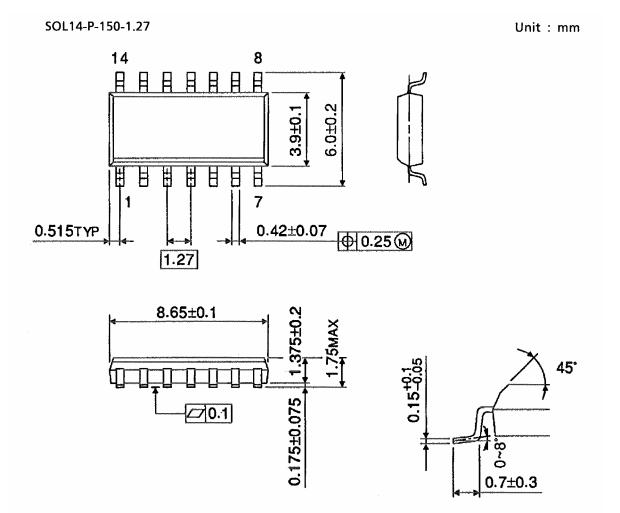
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

# Package Dimensions (Note)



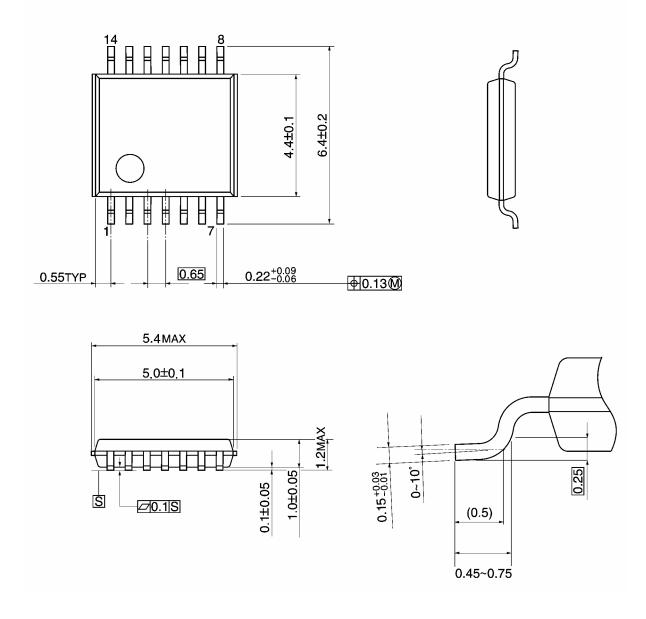
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

# Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



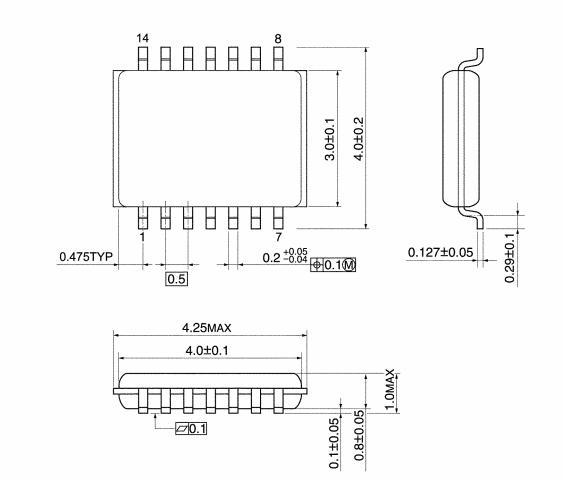
Weight: 0.06 g (typ.)

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#### Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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